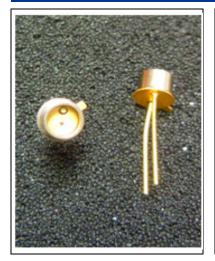
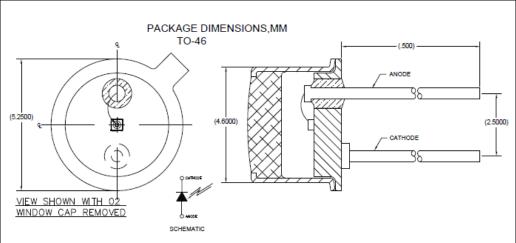


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Precision – Control – Results





DESCRIPTION

The **SD012-121-011** is a high sensitivity, low capacitance and noise, 0.3mm diameter active area InGaAs photodiode, sensitive to wavelengths in visible extended (450-1700nm) spectral range and used for sensing applications. The photodetector is assembled in a TO-46 package.

RELIABILITY

This API high-reliability detector is in principle able to meet military test requirements (Mil-STD-750, Mil-STD-883) after proper screening and group test.

Contact API for recommendations on specific test conditions and procedures.

MOISTURE SENSITIVITY LEVEL

API silicon light dependent resistors are classified as MSL level 1 per J-STD-020 allowing for unlimited floor time at temperatures less than or equal to $30\,^{\circ}$ C and humidity less than or equal to 85%.

ABSOLUTE MAXIMUM RATINGS

SYMBOL	MIN	MAX	UNITS
Operating Temperature	0	+85	℃
Storage Temperature	-25	+85	∞
Soldering Temperature *	-	+240	.€
Wavelength Range	450	1700	nm
Reverse Voltage	-	20	V

^{*) 1/16} inch from case for 3s max.

FEATURES

- Low Noise
- Low Dark Current and Capacitance
- High Sensitivity
- Light Detection (Visible, NIR, SWIR)

APPLICATIONS

- Industrial Sensing
- · Security and Defense
- Communication

ESD

This device is Class 1A (HBM).

T_a = 23 °C non condensing

SD012-121-011



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OPTO-ELECTRICAL PARAMETERS

Precision – Control – Results

T_a = 23 °C unless noted otherwise

PARAMETER	TEST CONDITIONS	MIN	
Breakdown Voltage	$I_{\text{bias}} = 100 \mu A$	10	
Responsivity	λ= 600 nm	0.3	•

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Breakdown Voltage	$I_{\text{bias}} = 100 \mu\text{A}$	10	-	-	V
Responsivity	λ= 600 nm	0.3	0.35	-	A/W
Responsivity	λ= 1200 nm	0.7	0.85	-	A/W
Responsivity	λ= 1550 nm	0.9	1.00	-	A/W
Shunt Resistance	V _{bias} = 10 mV	5	30	-	ΜΩ
Dark Current	$V_{\text{bias}} = 1V$	-	2	20	nA
Capacitance	$V_{\text{bias}} = 1V$; $f = 1 \text{ MHz}$	-	6	20	pF
Rise Time (50 Ω load)	$V_{bias} = 1V; \lambda = 826 \text{ nm}$	-	5	-	ns
Noise Equivalent Power	λ= 900 nm	-	1.0	-	10 ⁻¹³ W/Hz ^{0.5}

TYPICAL PERFORMANCE

SPECTRAL RESPONSE

